

FAST RECOVERY RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V

CURRENT: 2.5 A

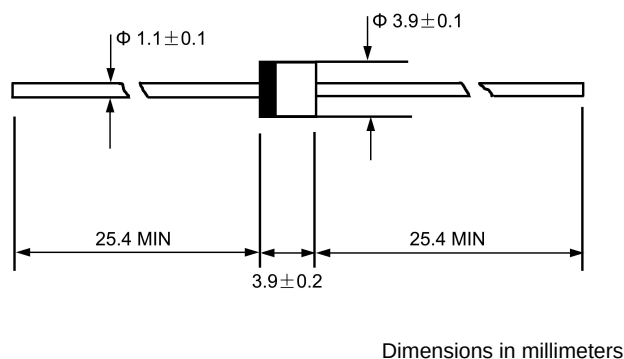
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Freon, Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC R-3, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.021 unces, 0.58 grams
- ◇ Mounting position: Any

R - 3



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		FR 251	FR 252	FR 253	FR 254	FR 255	FR 256	FR 257	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forw ard rectified current 9.5mm lead length, @T _A =75°C	I _{F(AV)}	2.5							A
Peak forw ard surge current 8.3ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	150.0							A
Maximum instantaneous forw ard voltage @ 2.5 A	V _F	1.3							V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	5.0 100.0							μ A
Maximum reverse recovery time (Note1)	t _{rr}	150				250	500		ns
Typical junction capacitance (Note2)	C _J	22							pF
Typical thermal resistance (Note3)	R _{θJA}	35							°C/W
Operating junction temperature range	T _J	- 55---- +150							°C
Storage temperature range	T _{STG}	- 55---- + 150							°C

NOTE:1. Measured with $I_F = 0.5\text{A}$, $I_R = 1\text{A}$, $t_{rr} = 0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance from junction to ambient.

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FIG.1 – TYPICAL FORWARD DERATING CURVE

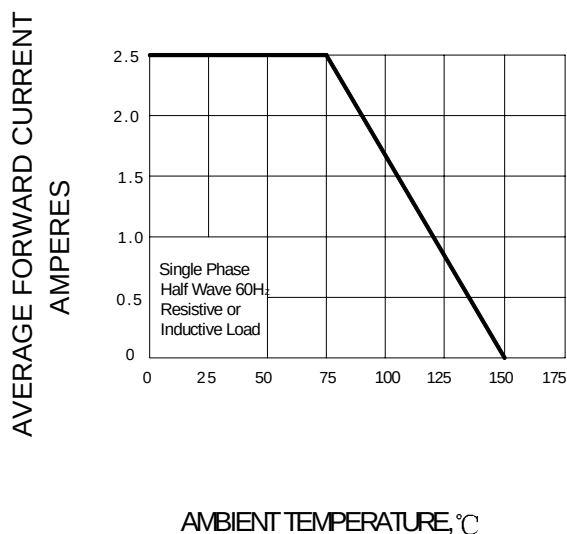


FIG.2- FORWARD SURGE CURRENT

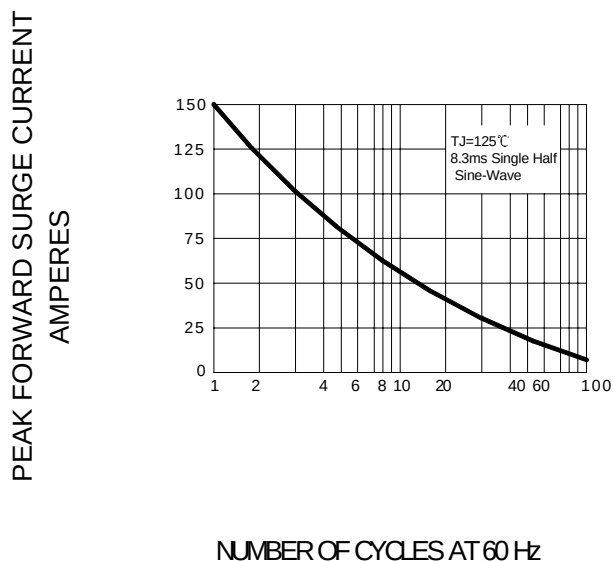


FIG.3-TYPICAL JUNCTION CAPACITANCE

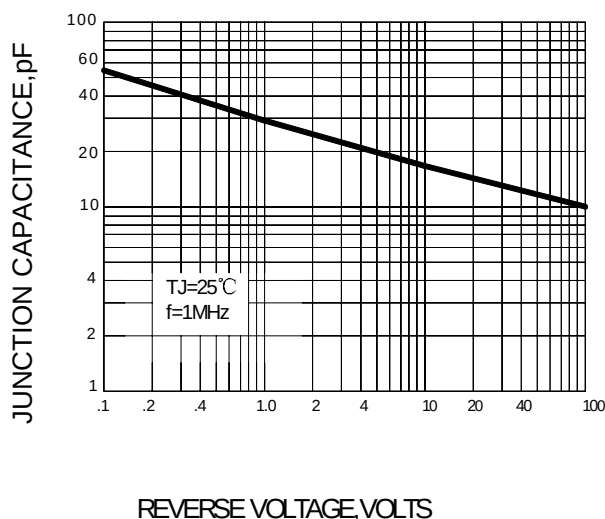


FIG.4 –TYPICAL FORWARD CHARACTERISTIC

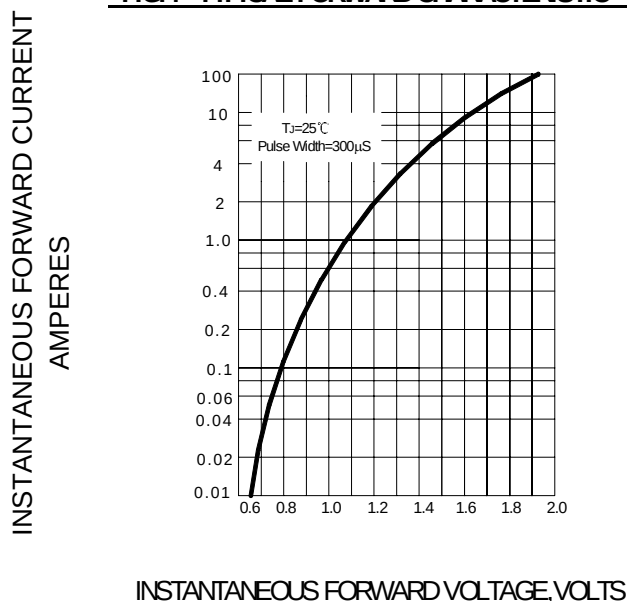
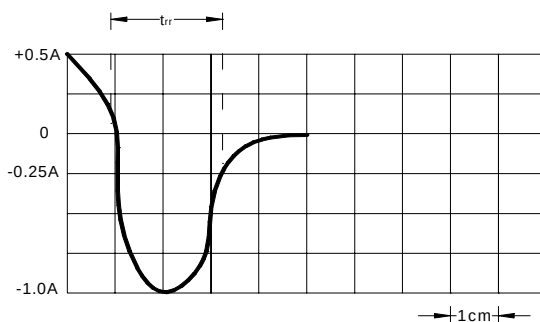
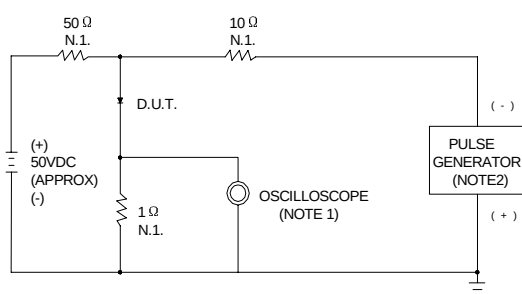


FIG.5 – REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES:1.RISE TIME=7ns MAX. INPUT IMPEDANCE=1MΩ.22pF

2.RISE TIME=10ns MAX. SOURCE IMPEDANCE=50Ω

SET TIME BASE FOR 50/100 ns /cm